

SPICE Device Model TN0200K Vishay Siliconix

N-Channel 20-V (D-S) MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

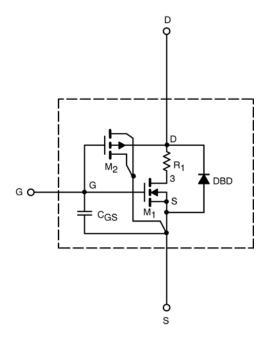
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0-V to 5-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

Document Number: 72863 www.vishay.com S-52292—Rev. B, 31-Oct-05

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| SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED) | | | | | |
|---|---------------------|---|-------------------|------------------|--------------|
| Parameter | Symbol | Test Condition | Simulated Data | Measured Data | Unit |
| Static | - | | · | | - |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 50 \mu A$ | 0.60 | 0.60 | V |
| On-State Drain Current ^a | I _{D(on)} | V _{DS} = 5 V, V _{GS} = 4.5 V | 29 | | Α |
| Drain-Source On-State Resistance ^a | Γ _{DS(on)} | V_{GS} = 4.5 V, I_{D} = 0.60 A | 0.18 | 0.20 | |
| | | V_{GS} = 2.5 V, I_D = 0.60 A | 0.24 | 0.25 | |
| Forward Transconductance ^a | g _{fs} | V _{DS} = 5 V, I _D = 0.60 A | 1.8 | 2.2 | S |
| Diode Forward Voltage ^a | V_{SD} | I _S = 0.30 A, V _{GS} = 0 V | 0.74 | 0.80 | V |
| Dynamic ^b | | | <u>-</u> | | |
| Total Gate Charge | Q_g | V _{DS} = 10 V, V _{GS} = 4.5 V, I _D = 0.60 A | 1.2 | 1.4 | nC |
| Gate-Source Charge | Q_{gs} | | 0.19 | 0.19 | |
| Gate-Drain Charge | Q_{gd} | | 0.30 | 0.30 | |
| Turn-On Delay Time | t _{d(on)} | $V_{DD} = 10 \text{ V, R}_L = 16 \Omega$ $I_D \cong 0.60 \text{ A, V}_{GEN} = 4.5 \text{ V, R}_G = 10 \Omega$ | 16 | 17 | ns ns |
| Rise Time | t _r | | 18 | 20 | |
| Turn-Off Delay Time | t _{d(off)} | | 35 | 55 | |
| Fall Time | t _f | | 35 | 30 | |

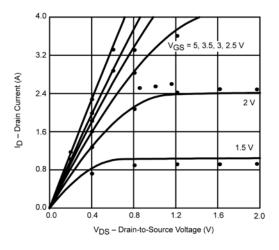
Notes

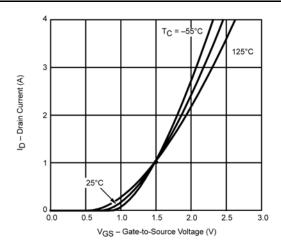
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing.

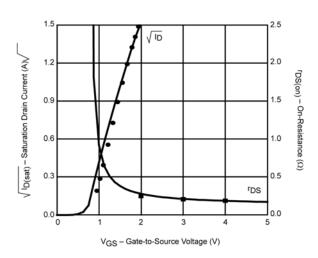


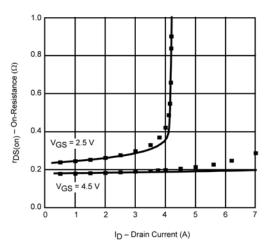
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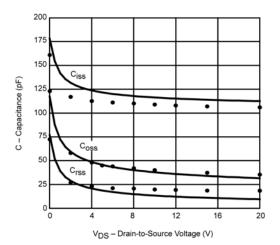
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

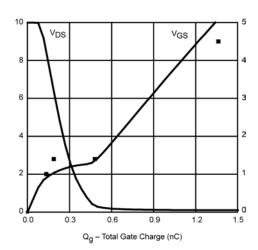












Note: Dots and squares represent measured data



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Document Number: 91000 Revision: 18-Jul-08

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